



Docket No.: M4065.0210/P210-A
(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:
Sam Yang et al.

Application No.: 10/002,176

Confirmation No.: 3795

Filed: December 5, 2001

Art Unit: 2814

For: METHOD OF FORMING A CAPACITOR
FOR A SEMICONDUCTOR DEVICE

Examiner: H. B. Trinh

FIRST PRELIMINARY AMENDMENT

MS Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

INTRODUCTORY COMMENTS

Prior to examination on the merits, please amend the above-identified U.S. patent application as follows:

Amendments to the Claims are reflected in the listing of claims which begins on page 2 of this paper.

Remarks begin on page 9 of this paper.